

Drift = Diffusion + Einstein Relation

$$\phi_0 = V_{TH} \ln \frac{N_A N_D}{n_i^2}$$

write  $N_A, N_D$  as  $10^x n_i, 10^y n_i$   
 $N_A = 10^x n_i = 10^x 10^{10} = 10^{10+x}$   
 $N_D = 10^{10+y}$

Gauss  
 $\int E \cdot ds = \frac{Q}{\epsilon}$

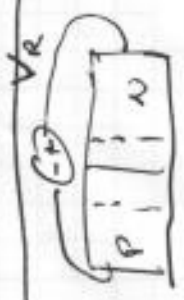
$V = -\int E dx$

$$\phi_0 = V_{TH} \ln \left( \frac{10^x n_i 10^y n_i}{n_i^2} \right)$$

$$= V_{TH} \ln 10^{(x+y)} =$$

$$= V_{TH} \ln(10) (x+y)$$

60mV @ R.T.  
 memorize!



Reverse bias

linear increase in depletion width gives

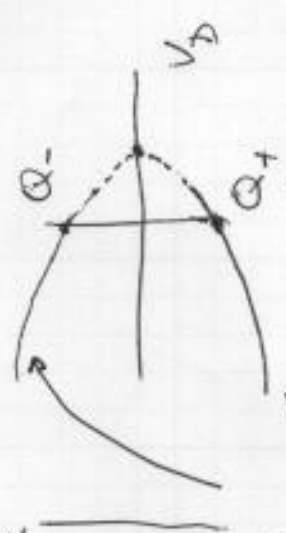
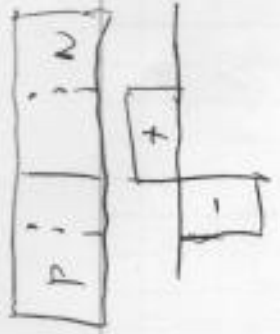
" " in charge

" " in peak field  $\Rightarrow$

quadratic increase in potential

$(\phi_0 + \phi_k)^2 \sim$  field, charge, width

$\Rightarrow$  field, charge, width  $\sim \sqrt{\phi_0 + \phi_k} = \sqrt{\phi_0 - V_D}$



$$Q \sim \sqrt{\phi_0 + V_R}$$

$$C_j = \frac{dQ}{dV_R} = \frac{C_{j0}}{\sqrt{1 + V_R/\phi_0}}$$

OK in fwd bias to  $\approx \frac{\phi_0}{2}$



$$V_D \rightarrow P \quad n_p = n_i^2$$

when  $V_D < 0$ , current is due to minority carriers on the lightly doped side hitting the E-field and falling down the potential well (usual  $\pm$  index of reverse bias until breakdown) = I



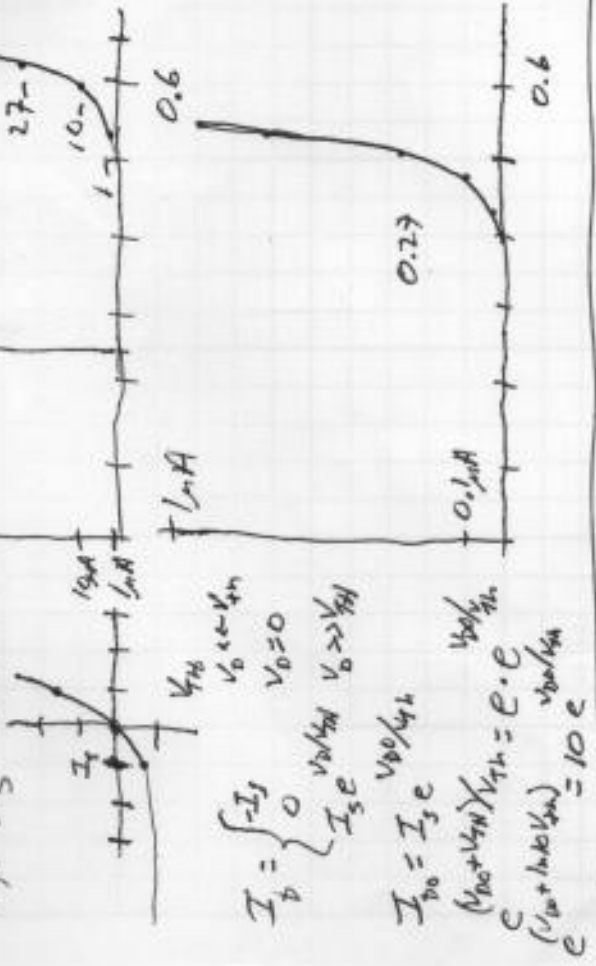
Varactor

If  $V_D \sim 10 \times \phi_0 \Rightarrow 3 \times$  variation in C

when  $V_D = 0$  diffusion = drift  $I_s$   
 huge conc. gradient  
 held back by E-field

Just the highest energy particles get across  
 Fwd bias,  $V_D > 0$  lowers energy barrier  
 Fermi-Dire distribution of energy  $\sim e^{-E/kT}$   
 conc w/ energy greater than  $X: n e^{-E/kT}$   
 Result:  $I_D = I_s (e^{V_D/kT} - 1)$

P.S.  $I_S = 10^{-15} A = 1 fA$

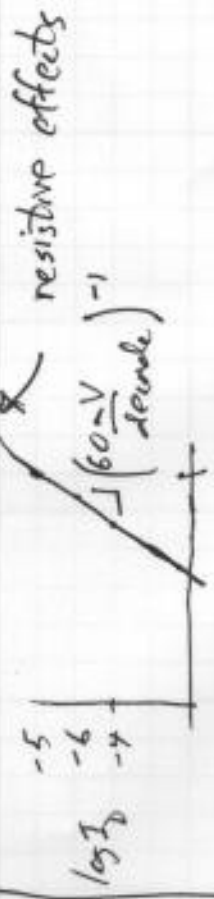


$$I_b = \begin{cases} -I_S & V_b \leftarrow V_{th} \\ 0 & V_b = 0 \\ I_S e^{V_b/V_{th}} & V_b \rightarrow V_{th} \end{cases}$$

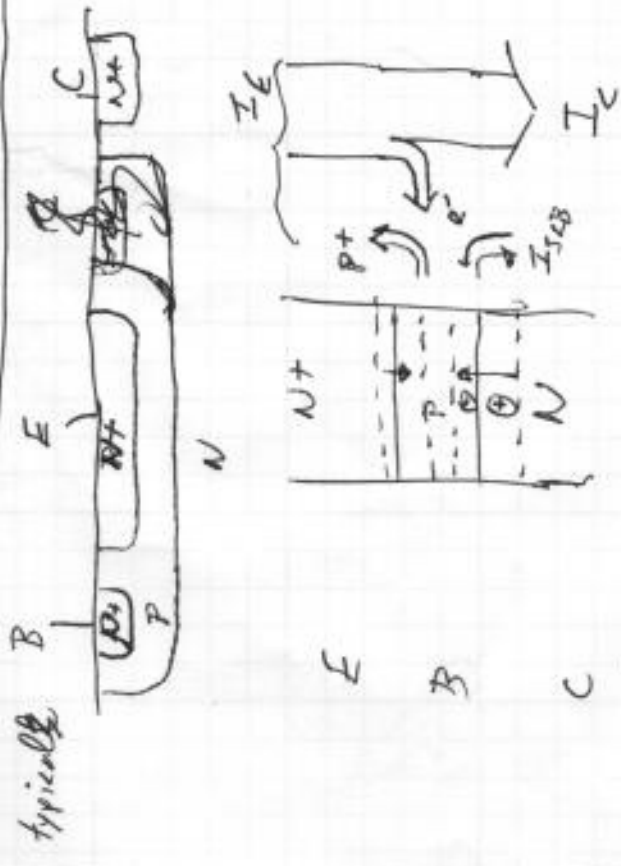
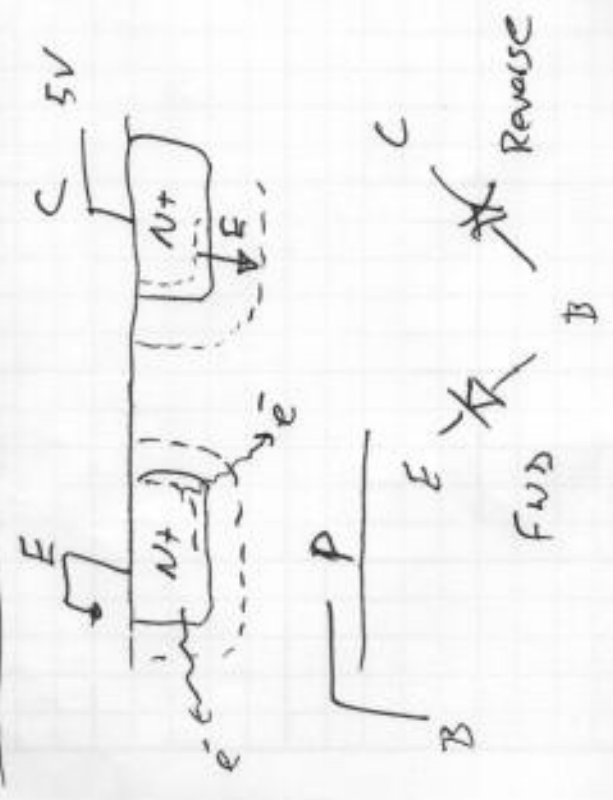
$$I_{b0} = I_S e^{V_{b0}/V_{th}}$$

$$\frac{(V_{b0} + V_{th})}{V_{th}} = e \cdot e$$

$$\frac{(V_{b0} + V_{th})}{V_{th}} = 10 e$$



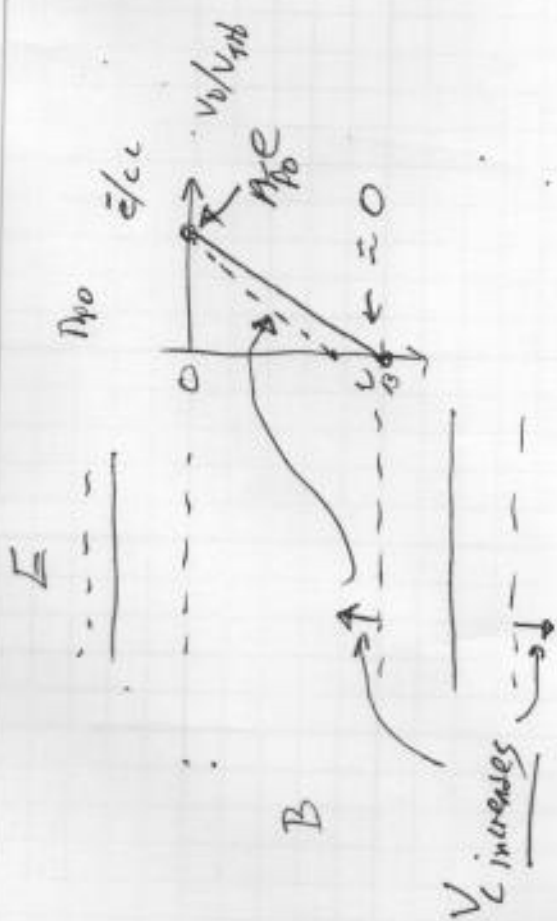
resistive effects



$$I_C = \beta I_B$$

$$I_C = I_{C0} e^{V_{BE}/V_{th}}$$

what is  $V_{BE0}$ ?



$$I_C = I_S e^{\frac{V_{BE}}{V_{TH}}} \left(1 + \frac{V_{CE}}{V_A}\right)$$

$$g_m = \frac{\partial I_C}{\partial V_{BE}} = \frac{I_C}{V_{TH}}$$

$$r_{\pi} = \frac{1}{g_m}$$

$$g_{\pi} = \frac{\partial I_B}{\partial V_{BE}} = \frac{\partial}{\partial V_{BE}} \left( \frac{I_C}{\beta} \right) = \frac{g_m}{\beta}$$

$$r_{\pi} = \frac{\beta}{g_m}$$

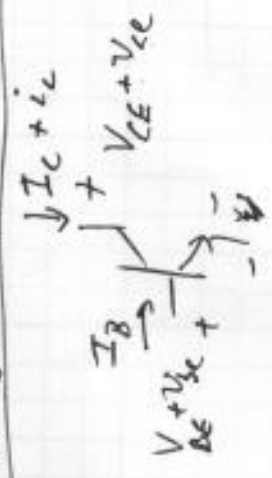
$$J_n = 2 D_n \frac{dn_p}{dx}$$

$$I_C = A_E J_n$$

$$W_B \sim \sqrt{\phi_0 + V_{CB}}$$

$$g_0 = \frac{\partial I_C}{\partial V_{CE}} \approx \frac{I_C}{V_A}$$

$$r_0 = \frac{1}{g_0} = \frac{V_A}{I_C} \leftarrow \text{Early voltage}$$



$V_{BE}, V_{CE}, I_C, I_B$  satisfy nonlinear eqn.  
 $v_{be}, v_{ce}, i_c$  are local linearizations (tangent slope)  
 $i_c = g_m v_{be} + \frac{1}{r_0} v_{ce}$   
 $g_m = \frac{1}{r_{\pi}} \frac{v_{be}}{v_{be}}$